Thyristor Semiconductor Device - Page 1 of 1



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**Inclosure Material:** Metal **Overall Length:** 0.502 inches **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 48.0 breakover voltage, dc **Current Rating Per Characteristic:** 25.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a Unit Of Measure: Demilitarization: No Fiig: A110a0